



PART - D

Answer any one. Each question carries weightage of 4.

23. Describe the constructor and operation of a FET. Define the parameter of the FET and obtain the relation between them.
24. Explain the working of a Colpitts oscillator and give the expression for frequency of oscillation and the condition for starting of oscillation. (1×4=4)



Reg. No. :

Name :

V Semester B.Sc. Degree (CCSS – Reg./Supple./Imp.)

Examination, November 2014

CORE COURSE IN PHYSICS

5B09 PHY : Basic Electronics

(2011 and Earlier Admissions)

Time : 3 Hours

Max. Weightage : 30

PART - A

Choose the correct answers. Each bunch carries a weightage of 1.

1. i) A transistor can act as a switch when it operate between
- cut off region and active region
 - active region and saturation region
 - cut off and saturation
 - none of the above
- ii) Beyond pinch-off voltage, the drain to source resistance of a JFET is
- zero
 - low
 - high
 - medium value
- iii) For a common emitter BJT, β is given by
- $\beta = \frac{\alpha}{1+\alpha}$
 - $\beta = \frac{\alpha}{1-\alpha}$
 - $\beta = \frac{1+\alpha}{1-\alpha}$
 - $\beta = \frac{\alpha^2}{1+\alpha}$
- iv) CE amplifier is characterized by
- low-voltage gain
 - small phase reversal
 - high power gain
 - very high output impedance

